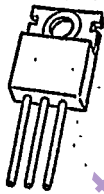


Reference No. SA01TY23

DIGITRON

092386



DGE

New part
DGE

092386

Triacs6A to 15A RMS Up to 600 Volts
Isolated and Non-Isolated Tab

M-04

ISOLATED TAB

SC140

SC142

SC147

NON-ISOLATED TAB

SC141

SC143

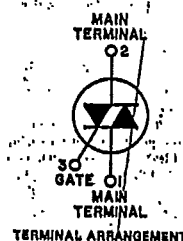
SC146

SC149

SC151

TYPE	RMS ON-STATE CURRENT, I _{T(RMS)} (1)	REPETITIVE PEAK OFF-STATE VOLTAGE, V _{DRM} (2)				PEAK ONE FULL CYCLE SURGE (NON-REP) ON-STATE CURRENT, I _{TSM} AMPERES		1 st FOR FUSING FOR TIMES AT(3)	
		B	D	E	M	50 Hz	60 Hz	(RMS AMPERE) ² SECONDS 1.0 MILLISECOND	(RMS AMPERE) SECONDS, 8 MILLISECOND
	AMPERES	VOLTS	VOLTS	VOLTS	VOLTS	AMPERES	AMPERES		
ISOLATED TAB									
SC140	6.5	200	400	500	600	74	80	18	26.5
SC142	8	200	400	500	600	104	110	20	50
SC147	10	200	400	500	600	104	110	20	50
NON-ISOLATED TAB									
SC141	6	200	400	500	600	74	80	18	26.5
SC143	8	200	400	500	600	110	120	20	60
SC146	10	200	400	500	600	110	120	20	60
SC149	12	200	400	500	600	110	120	20	60
SC151	15	200	400	500	600	110	120	20	60

ISOLATED TAB SC140, 2, 7	NON-ISOLATED 1 SC141, 3, 6, 9, SC
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CHARACTERISTICS

TEST	SYMBOL	MIN.	TYP.	MAX.	UNITS	TEST CONDITIONS
Repetitive Peak Off-State Current	I_{DRM}			0.1	mA	V_{DRM} = Maximum Allowable Repetitive Off-State Voltage Rating Gate Open Circuited $T_c = +25^\circ C$ $T_c = +100^\circ C$
Peak On-State Voltage	V_{TM}			1.85	Volts	$T_c = +25^\circ C$, $I_{TM} = 1$ msec, Wide Pulse, Duty Cycle $\leq 2\%$ $I_{TM} = 9.2$ A Peak $I_{TM} = 8.5$ A Peak $I_{TM} = 11.5$ A Peak $I_{TM} = 11.5$ A Peak $I_{TM} = 14$ A Peak $I_{TM} = 14$ A Peak $I_{TM} = 17$ A Peak $I_{TM} = 21$ A Peak
Critical Rate-of-Rise of Off-State Voltage (Higher values may cause device switching)	dv/dt				Volts/ μ sec	$T_c = +100^\circ C$, Rated V_{DRM} Gate Open Circuited Exponential Voltage Waveform
SC140, SC141		30	100			
SC142, SC143		50	150			
SC146, SC147		100	150			
SC149		100	200			
SC151		100	250			
Critical Rate-of-Rise of Commutating Off-State Voltage (Commutating dv/dt)	$dv/dt(c)$	4			Volts/ μ sec	$I_{T(RMS)}$ = Rated Maximum Allowable RMS On-State Current, V_{DRM} = Maximum Rated Peak Off-State Voltage, Gate Open Circuited.
DC Gate Trigger Current	I_{GT}			50	mA	$V_D = 12$ Vdc TRIGGER MODE R_L T_c MT2+ Gate + 100 Ohms MT2- Gate - 100 Ohms MT2+ Gate - 50 Ohms MT2- Gate + 50 Ohms MT2- Gate - 50 Ohms MT2+ Gate - 25 Ohms
DC Gate Trigger Voltage	V_{GT}			2.5	Vdc	$V_D = 12$ Vdc TRIGGER MODE R_L T_c MT2+ Gate + 100 Ohms MT2- Gate - 100 Ohms MT2+ Gate - 50 Ohms MT2- Gate + 50 Ohms MT2- Gate - 50 Ohms MT2+ Gate - 25 Ohms
DC Gate Non-Trigger Voltage	V_{DN}	0.2			Vdc	TRIGGER MODE R_L T_c MT2+ Gate + 1000 Ohms MT2- Gate - 1000 Ohms MT2+ Gate +

ISOLATED TAB SC140, 2, 7	NON-ISOLATED TAB SC141, 3, 6, 9, SC151
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TEST	SYMBOL	MIN.	TYP.	MAX.	UNITS	TEST CONDITIONS
DC Holding Current	I_H			50	mA	Main Terminal Source Voltage = 24 Vdc Gate Initiating On-State Current = 0.1 millisecond to 10 millisecond wide pulse, Gate Trigger Source = 20 Ohms $T_c = +25^\circ C$ $T_c = -40^\circ C$
DC Latching Current	I_L			100	mA	Main Terminal Source Voltage = 24 Vdc Gate Trigger Source = 15V, 100 Ohms 50 μ sec pulse width, 5 μ sec rise and fall times maximum
Steady State Thermal Resistance	$R_{\theta JA}$			75	$^\circ C/Watt$	Junction-to-Ambient
Steady State Thermal Resistance	$R_{\theta JC}$				$^\circ C/Watt$	Junction-to-Case
SC140				3.1		
SC141				3.0		
SC142				3.3		
SC143				3.2		
SC146				2.2		
SC147				2.5		
SC149				2.0		
SC151				2.0		
Apparent Thermal Resistance	$R_{\theta JCA}$				$^\circ C/Watt$	Junction-to-Case This characteristic is useful as an acceptance test at an incoming inspection station.
SC140				2.04		
SC141				2.22		
SC142				2.31		
SC143				1.97		
SC146				1.50		
SC147				1.69		
SC149				1.52		
SC151				1.10		

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